

#14
9/15/03
Mullish
PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Ko et al.

Serial No.: 09/585,682

Filed: June 1, 2000

For: SEMICONDUCTOR DEVICE
HAVING A SUBSTRATE, AN UNDOPED
SILICON OXIDE STRUCTURE, AND AN
OVERLYING DOPED SILICON OXIDE
STRUCTURE WITH A SIDEWALL
TERMINATING AT THE UNDOPED
SILICON OXIDE STRUCTURE (Amended)

Confirmation No.: 7481

Examiner: C. Chu

Group Art Unit: 2815

Attorney Docket No.: 2269-3526.2US
(97-1136.02/US)

CERTIFICATE OF MAILING

I hereby certify that this correspondence along with any attachments referred to or identified as being attached or enclosed is being deposited with the United States Postal Service as First Class Mail on the date of deposit shown below with sufficient postage and in an envelope addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

August 29, 2003
Date

Signature

Deidra J. Pfeil
Name (Type/Print)

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In compliance with the duty to disclose information material to patentability pursuant to 37 C.F.R. § 1.56, it is respectfully requested that this Supplemental Information Disclosure Statement be entered and the documents listed on attached Form PTO-1449 be considered by the Examiner and made of record. Copies of the listed documents are enclosed pursuant to 37 C.F.R. § 1.98(a).

In accordance with 37 C.F.R. § 1.97(g) and (h), filing of this Supplemental Information Disclosure Statement is not to be construed as a representation that a search has been made or an admission that the information cited herein is, or is considered to be, material to patentability as defined in 37 C.F.R. § 1.56(b). Further, no representation is made by Applicants herein that no other possible material information as defined in 37 C.F.R. § 1.56 (b) exists.

U.S. Patent Documents

<u>U.S. Patent No.</u>	<u>Publication Date</u>	<u>Patentee</u>
4,529,476	07/1985	Kawamoto et al.
6,018,184	01/2000	Becker
6,066,555	05/2000	Nulty et al.
6,117,791	09/2000	Ko et al.
6,277,720 B1	08/2001	Doshi et al.
6,303,496 B1	10/2001	Yu

Foreign Patent Documents

<u>Document No.</u>	<u>Publication Date</u>	<u>Patentee</u>
61251138	08/1986	JP
0721205 A2	07/1996	EPO
WO 98/49719	11/1998	PCT

Other Documents

Wolf, S., et al., Silicon Processing for the VLSI Era, Vol. 1, Process Technology, Lattice Press, 1986, pp. 520-523.

Williams, K., BSAC Etch Rates for Micromachining and IC Processing, U.C. Berkeley Microfabrication Lab., Berkeley Sensor & Actuator Center, <http://www-bsac.eecs.berkeley.edu/db/etchrates.html>.

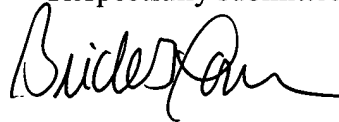
Williams, K., VLSI Etchants, Chapter 1.5, Rev. 11/97, <http://microlab.berkeley.edu/labmanual/chap1/1.5.html>.

Applicants offer to supply any explanation or discussion of the documents which the Examiner feels is necessary or desirable and which is requested.

This Supplemental Information Disclosure Statement is filed after the mailing date of the first Office Action on the merits.

The fee pursuant to 37 C.F.R. § 1.17(p) is enclosed.

Respectfully submitted,



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Date: August 29, 2003
BGP/ps:djp

Enclosures: Form PTO-1449
Copy of documents cited
Check No. 4880 in the amount of \$180.00

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